## Docket No.

## ARENT FOX KINTNER PLOTKIN & KAHN, PLLC

## Declaration For U.S. Patent Application

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below my name.

the specification of which is attached hereto unless the following box is checked:

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled (Insert Title)

METHOD FOR FORMING POROUS SILICA FILM

	was filed on		As PCT International Application							
	Number	•	and was amended on							
And/or	was filed	d on	As United States Application							
	Number		and was amended on .							
I hereby any amen	state that I	I have erred t	reviewed and understa o above.	and the conter	nts of the above-io	lentified spec	ification, includ	ling the cla	im(s), as amended by	
I acknow	ledge the	duty to	disclose information	which is mater	rial to patentabilit	y as defined in	n 37 C.F.R. §1	56.		
I hereby certificate and have date befo	claim for e, or §365 also iden ore that of t	reign p (a) of tified l the app	priority benefits under any PCT International below any foreign app plication(s) for which p	35 U.S.C. § application wellication for partical in claim	\$119(a)-(d) or \$30 which designated a atent or inventor's med:	65(b) of any at least one concertificate or	foreign applic ountry other tha r PCT Internati		patent or inventor's d States, listed below cation having a filing	
	_24	<del>1719</del> 0/	2002 J	apan	27 Au	gust 2002		Priority C	laimed  No	
(List pri		ımber)	(Co	ountry)	(Day/Month/Year Filed)					
foreign applicat	tions) $\frac{03}{}$	32189/	9/2003 Japan		10 February 2003			Yes No		
	(Ma	imberj	(Ci	ountry)	(Day/Month/Year Filed)					
I hereby claim the benefit under 35 U.S.C. §119(e) of any United States provisional application(s) listed below.										
		(App	olication Number)		(Filing Date)			-		
		(App	lication Number)		(Filing Date)	***************************************		-		
See attached list for additional prior foreign or provisional applications.										
I hereby claim the benefit under 35 U.S.C. §120 of any United States application(s) or §365(c) of any PCT International application(s) designating the United States of America listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior application(s) (U.S. or PCT) in the manner provided by the first paragraph of 35, U.S.C. §112, I acknowledge the duty to disclose information which is material to patentability as defined in 37 C.F.R. §1.56 which became available between the filing date of the prior application and the national or PCT International filing date of this application.										
(List prior U	J.S.									
Applications PCT Interna applications	tional	(App	Application Serial No.)		(Filing Date)		(Status) (patented, pending, abandoned)			
applications designating	the U.S.)	(App	olication Serial No.)		(Filing Date)		(Status) (patented, pending, abandoned)			
And I he 22,980; C Reg. No. Reg. No. A. Kidne Charles B	reby appo Charles M. 44,275; R 48,898; B y, Reg. No Buskey, Re	oint the Marm cobert rian A o. 46,1 g. No.	e firm of Arent Fox, elstein, Reg. No. 25,89 K. Carpenter, Reg. No. 4 Tollefson, Reg. No. 4 95; Bala Sundararajar 46,592.	Customer Nur 95; George E. 6, 34,794; Rus 6,338, Lynne 1, Reg. No. P.	mber <b>004372</b> inc Oram, Jr., Reg. No tan Hill, Reg. No D. Anderson, Reg 50,900; Monica K	uding as prino. 27,931; Rio. 37,351; Hang. No. 46,412; itts, Reg. No.	ncipal attorneys chard J. Berman is J. Crosby, Re D. Daniel Dza . 36,105; King	s: Robert I n, Reg. No. eg. No. 44,6 ra, II, Reg. L. Wong, I	B. Murray, Reg. No. 39,107; Murat Ozgu, 534, Lynn A. Bristol, No. 47,543, Jonathan Reg. No. 37,500; and	
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The undersigned hereby authorizes the U.S. attorneys named herein to accept and follow instructions from the undersigned's assignee, if any, and/or, if the undersigned is not a resident of the United States, the undersigned's domestic attorney, patent attorney or patent agent, as to any action to be take in the Patent and Trademark Office regarding this application without direct communication between the U.S. attorneys and the undersigned. In the event of a change in the person(s) from whom instructions may be taken, the U.S. attorneys named herein will be so notified by the undersigned.

Telephone No. (202) 857-6000; Facsimile No. (202) 638-4810

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further, that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.



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